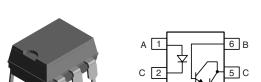


Vishay Semiconductors

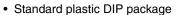
Optocoupler, Photodarlington Output, High Gain, with Base Connection



NC 3

FEATURES

- Very high current transfer ratio, 500 % min.
- High isolation resistance, $10^{11} \Omega$ typical





 Component in accordance to RoHS 2002/95/EC and WEEE 2002/96/EC







DESCRIPTION

The 4N32 and 4N33 are optically coupled isolators with a gallium arsenide infrared LED and a solicon photodarlington sensor.

Switching can be achieved while maintaining a high degree of isolation between driving and load circuits.

These optocouplers can be used to replace reed and mercury relays with advantages of long life, high speed switching and elimination of magnetic fields.

AGENCY APPROVALS

- UL1577, file no. E52744 system code H or J, double protection
- DIN EN 60747-5-2 (VDE 0884)/DIN EN 60747-5-5 pending available with option 1
- BSI IEC60950; IEC60065

ORDER INFORMATION				
PART	REMARKS			
4N32-X000	CTR > 500 %, DIP-6			
4N33-X000	CTR > 500 %, DIP-6			
4N32-X007	CTR > 500 %, SMD-6 (option 7)			
4N32-X009	CTR > 500 %, SMD-6 (option 9)			
4N33-X007	CTR > 500 %, SMD-6 (option 7)			
4N33-X009	CTR > 500 %, SMD-6 (option 9)			

Note

For additional information on the available options refer to option information.

ABSOLUTE MAXIMUM RATINGS (1)							
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT			
INPUT							
Reverse voltage		V_{R}	3	V			
Forward current		I _F	60	mA			
Power dissipation		P _{diss}	100	mW			
Derate linearly	from 55 °C		1.33	mW/°C			
OUTPUT							
Collector emitter breakdown voltage		BV _{CEO}	30	V			
Emitter base breakdown voltage		BV _{EBO}	8	V			
Collector base breakdown voltage		BV _{CBO}	50	V			
Emitter collector breakdown voltage		BV _{ECO}	5	V			
Collector (load) current		I _C	125	mA			
Power dissipation		P _{diss}	150	mW			
Derate linearly			2	mW/°C			

4N32-X000/4N33-X000

Vishay Semiconductors Optocoupler, Photodarlington Output, High Gain, with Base Connection



ABSOLUTE MAXIMUM RATINGS (1)						
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT		
COUPLER						
Total dissipation		P _{tot}	250	mW		
Derate linearly			3.3	mW/°C		
Isolation test voltage (between emitter and detector, standard climate: 23 °C/ 50 % RH,\\nDIN 500 14)		V _{ISO}	5300	V _{RMS}		
Leakage path			7.0	mm min.		
Air path			7.0	mm min.		
Isolation resistance	$V_{IO} = 500 \text{ V}, T_{amb} = 25 ^{\circ}\text{C}$	R _{IO}	≥ 10 ¹²	Ω		
isolation resistance	V_{IO} = 500 V, T_{amb} = 100 °C	R _{IO}	≥ 10 ¹¹	Ω		
Storage temperature		T _{stg}	- 55 to + 150	°C		
Operating temperature		T _{amb}	- 55 to + 100	°C		
Lead soldering time (2)	at 260 °C		10	S		

Notes

⁽²⁾ Refer to reflow profile for soldering conditions for surface mounted devices (SMD). Refer to wave profile for soldering conditions for through hole devices (DIP).

ELECTRICAL CHARACTERISTICS (1)							
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT	
INPUT							
Forward voltage	I _F = 50 mA	V _F		1.25	1.5	V	
Reverse current	$V_{R} = 3.0 \text{ V}$	I _R		0.1	100	μΑ	
Capacitance	$V_R = 0 V$	Co		25		pF	
OUTPUT							
Collector emitter breakdown voltage (2)	$I_C = 100 \ \mu A, \ I_F = 0$	BV _{CEO}	30			V	
Collector base breakdown voltage (2)	$I_C = 100 \ \mu A, \ I_F = 0$	BV _{CBO}	50			V	
Emitter base breakdown voltage (2)	$I_C = 100 \ \mu A, \ I_F = 0$	BV _{EBO}	8			V	
Emitter collector breakdown voltage (2)	$I_C = 100 \ \mu A, \ I_F = 0$	BV _{ECO}	5	10		V	
Collector emitter leakage current	$V_{CE} = 10 \text{ V}, I_F = 0$	I _{CEO}		1.0	100	nA	
	$I_C = 0.5 \text{ mA}, V_{CE} = 5.0 \text{ V}$	h _{FE}	13				
COUPLER							
Collector emitter saturation voltage		V _{CEsat}		1.0	_	V	
Coupling capacitance				1.5		pF	

Notes

Minimum and maximum values are testing requirements. Typical values are characteristics of the device and are the result of engineering evaluation. Typical values are for information only and are not part of the testing requirements.

⁽²⁾ Indicates JEDEC registered values.

CURRENT TRANSFER RATIO						
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
Current transfer ratio	$V_{CE} = 10 \text{ V}, I_F = 10 \text{ mA}$	CTR	500			%

SWITCHING CHARACTERISTICS						
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
Turn-on time	$V_{CC} = 10 \text{ V}, I_{C} = 50 \text{ mA}$	t _{on}			5.0	μs
Turn-off time	$I_F = 200 \text{ mA}, R_L = 180 \Omega$	t _{off}			100	μs

⁽¹⁾ T_{amb} = 25 °C, unless otherwise specified.

Stresses in excess of the absolute maximum ratings can cause permanent damage to the device. Functional operation of the device is not implied at these or any other conditions in excess of those given in the operational sections of this document. Exposure to absolute maximum ratings for extended periods of the time can adversely affect reliability.

 $^{^{(1)}}$ T_{amb} = 25 $^{\circ}$ C, unless otherwise specified.



Optocoupler, Photodarlington Output, Vishay Semiconductors High Gain, with Base Connection

SAFETY AND INSULATION RATINGS							
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT	
Climatic classification (according to IEC 68 part 1)				55/100/21			
Comparative tracking index		CTI	175		399		
V _{IOTM}			8000			V	
V _{IORM}			890			V	
P _{SO}					700	mW	
I _{SI}					400	mA	
T _{SI}					175	°C	
Creepage distance	standard DIP-6		7			mm	
Clearance distance	standard DIP-6		7			mm	
Creepage distance	400 mil DIP-6		8			mm	
Clearance distance	400 mil DIP-6		8			mm	
Insulation thickness, reinforced rated	per IEC 60950 2.10.5.1		0.4			mm	

Note

As per IEC 60747-5-2, § 7.4.3.8.1, this optocoupler is suitable for "safe electrical insulation" only within the safety ratings. Compliance with the safety ratings shall be ensured by means of protective circuits.

TYPICAL CHARACTERISTICS

T_{amb} = 25 °C, unless otherwise specified

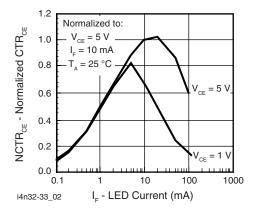


Fig. 1 - Normalized Non-Saturated and Saturated CTR $_{\rm CE}$ vs. LED Current

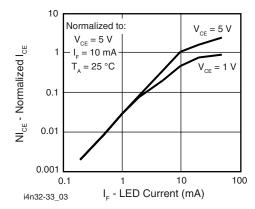


Fig. 2 - Normalized Non-Saturated and Saturated Collector Emitter Current vs. LED Current

Vishay Semiconductors Optocoupler, Photodarlington Output, High Gain, with Base Connection



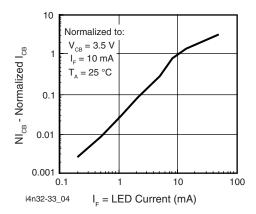


Fig. 3 - Normalized Collector Base Photocurrent vs. LED Current

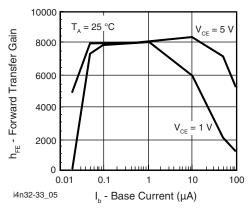


Fig. 4 - Non-Saturated and Saturated h_{FE} vs. Base Current

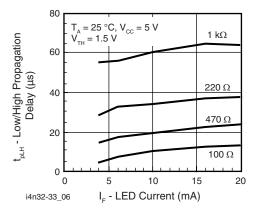


Fig. 5 - Low to High Propagation Delay vs. Collector Load Resistance and LED Current

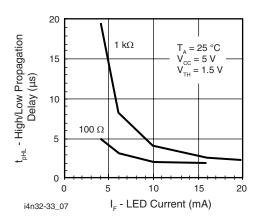


Fig. 6 - High to Low Propagation Delay vs. Collector Load Resistance and LED Current

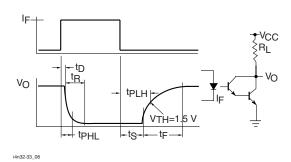


Fig. 7 - Switching Waveform and Switching Schematic



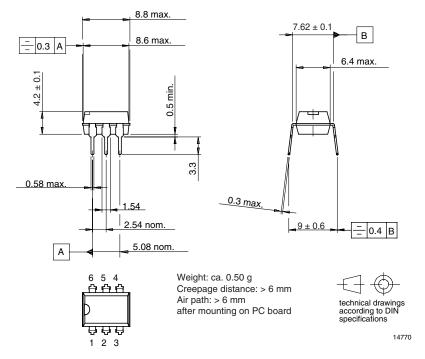
Optocoupler, Photodarlington Output, Vishay Semiconductors High Gain, with Base Connection

PACKAGE DIMENSIONS in millimeters

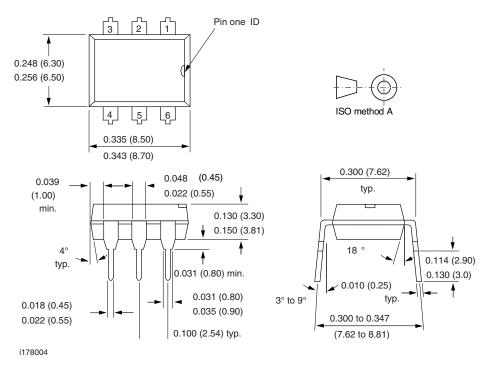
For 4N32/33.... see DIL300-6 Package dimension in the package section.

For products with an option designator (e.g. 4N32-X007 or 4N33-X009).... see DIP-6 Package dimensions in the package section.

DIL300-6 Package Dimensions

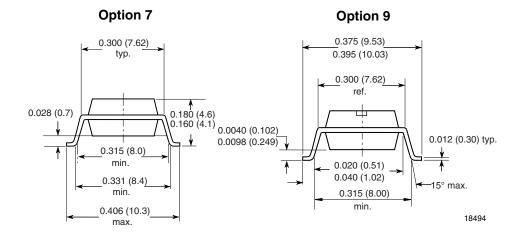


DIP-6 Package Dimensions





Vishay Semiconductors Optocoupler, Photodarlington Output, High Gain, with Base Connection





Optocoupler, Photodarlington Output, Vishay Semiconductors High Gain, with Base Connection

OZONE DEPLETING SUBSTANCES POLICY STATEMENT

It is the policy of Vishay Semiconductor GmbH to

- 1. Meet all present and future national and international statutory requirements.
- 2. Regularly and continuously improve the performance of our products, processes, distribution and operating systems with respect to their impact on the health and safety of our employees and the public, as well as their impact on the environment.

It is particular concern to control or eliminate releases of those substances into the atmosphere which are known as ozone depleting substances (ODSs).

The Montreal Protocol (1987) and its London Amendments (1990) intend to severely restrict the use of ODSs and forbid their use within the next ten years. Various national and international initiatives are pressing for an earlier ban on these substances.

Vishay Semiconductor GmbH has been able to use its policy of continuous improvements to eliminate the use of ODSs listed in the following documents.

- 1. Annex A, B and list of transitional substances of the Montreal Protocol and the London Amendments respectively.
- 2. Class I and II ozone depleting substances in the Clean Air Act Amendments of 1990 by the Environmental Protection Agency (EPA) in the USA.
- 3. Council Decision 88/540/EEC and 91/690/EEC Annex A, B and C (transitional substances) respectively.

Vishay Semiconductor GmbH can certify that our semiconductors are not manufactured with ozone depleting substances and do not contain such substances.

We reserve the right to make changes to improve technical design and may do so without further notice.

Parameters can vary in different applications. All operating parameters must be validated for each customer application by the customer. Should the buyer use Vishay Semiconductors products for any unintended or unauthorized application, the buyer shall indemnify Vishay Semiconductors against all claims, costs, damages, and expenses, arising out of, directly or indirectly, any claim of personal damage, injury or death associated with such unintended or unauthorized use.

Vishay Semiconductor GmbH, P.O.B. 3535, D-74025 Heilbronn, Germany

Document Number: 81865 Rev. 1.0, 11-Mar-08



Vishay

Disclaimer

All product specifications and data are subject to change without notice.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained herein or in any other disclosure relating to any product.

Vishay disclaims any and all liability arising out of the use or application of any product described herein or of any information provided herein to the maximum extent permitted by law. The product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein, which apply to these products.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay.

The products shown herein are not designed for use in medical, life-saving, or life-sustaining applications unless otherwise expressly indicated. Customers using or selling Vishay products not expressly indicated for use in such applications do so entirely at their own risk and agree to fully indemnify Vishay for any damages arising or resulting from such use or sale. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

Product names and markings noted herein may be trademarks of their respective owners.

Revision: 18-Jul-08

Document Number: 91000 www.vishay.com